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ABSTRACT: In recent years telescopes based to multilayer mirror technology have been employed in missions dedicated to the Sun observation in EUV wavelengths. Performances of multilayer are mainly evaluated in term of peak reflectivity at working wavelength and rejection capability of unwanted lines. Mo/Si multilayer are conventionally used for their high stability, but, when the structures are optimized for the 28.4 nm, the reflectivity is broadband and include the unwanted strong HeII line. A more narrowband solution has been obtained through an a-periodic design or using other material combinations. We propose an innovative method for designing suitable capping layer covering the multilayer which do not affect the reflectivity peak while rejecting unwanted lines. The capping layer solution can be adopted both in case of periodic and a-periodic multilayer, made by different materials. Thank to its flexibility, the design tool can provide innovative solutions with important improvement that can strongly affect the capability of the future solar instruments.

We show and discuss theoretical and experimental results of some coatings designed by the use of the new mathematical tool.
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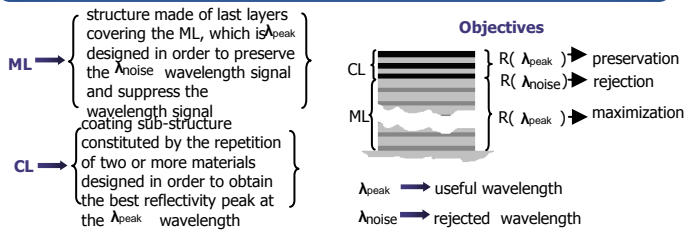
ANALYTICAL DESIGN METHOD

Basic principle

If a layer is grown at the node-position of the standing wave field intensity distribution the performance of the structure results essentially insensitive to the cap-layer absorption coefficient.

M. Suman et al., *Applied Optics*, Vol. 47, Issue 16, pp. 2906-2914 (2008).

Design method



Step 1

Design of the ML (periodic or a-periodic) in order to have the maximum reflectivity peak at λ_{peak}

parameters → period, γ optimized

Step 2

Computation of the standing wave in the ML structure for λ_{peak} wavelength, and also computation of the standing wave in the ML structure at λ_{noise} wavelength

Step 3

Optimization of the thicknesses and the number of the CL layers by growing the absorber layers into the Apeak standing wave nodes in order to preserve the reflectivity at the Apeak wavelength and as close as possible to the anti-nodes of the Anoise standing wave in order to efficiently reject the contribution at this wavelength

Step 4

Finally we optimize the CL layers and the ML period and γ parameters in order to improve the ratio $R(\lambda_{peak})/R(\lambda_{noise})$ while keeping high peak reflectivity.

SIMULATION OF SOME RESULTS

— standard periodic reflectivity
 — optimized multilayer reflectivity Simulations performed by IMD program

Case 1

Objectives parameters

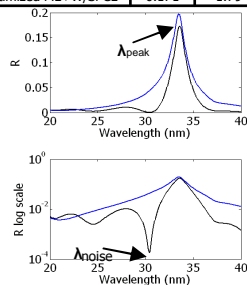
ML	CL	λ_{peak}	λ_{noise}
Mo/Si	W/Si	33.5	30.4

Results

	$R_{\lambda_{peak}}$	$R_{\lambda_{noise}}$
Standard periodic	0.197	0.044
Optimized ML+W/Si CL	0.171	$1.79 \cdot 10^{-4}$

Multilayer structures

CL Structure	Value
W	2.0 nm
a-Si	16.5 nm
W	2.2 nm
a-Si	16.5 nm
W	2.0 nm
a-Si	16.5 nm
ML structure	Value
Period (a-Si/Mo)	18.2 nm
Ratio	0.89
Period number	35



Case 2

Objectives parameters

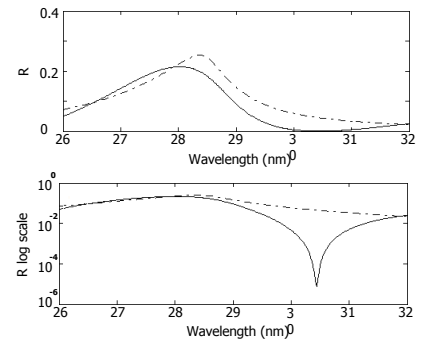
ML	CL	λ_{peak}	λ_{noise}
Mo/Si	Al/MgF ₂	28.4	30.4

Results

	$R_{\lambda_{peak}}$	$R_{\lambda_{noise}}$
Standard periodic	0.25	0.045
Optimized ML + Mo/Si CL	$0.1953.7 \cdot 10^{-5}$	$0.1953.7 \cdot 10^{-5}$

Multilayer structures

CL Structure	Value
MgF ₂ (thickness)	5 nm
Al (thickness)	10.25 nm
MgF ₂ (thickness)	3.5 nm
Al (thickness)	25.4 nm
MgF ₂ (thickness)	3.5 nm
ML structure	Value
Period d(a-Si/Mo)	15.33 nm
Ratio a-Si/d	0.77
number of periods	35



Case 3

Objectives parameters

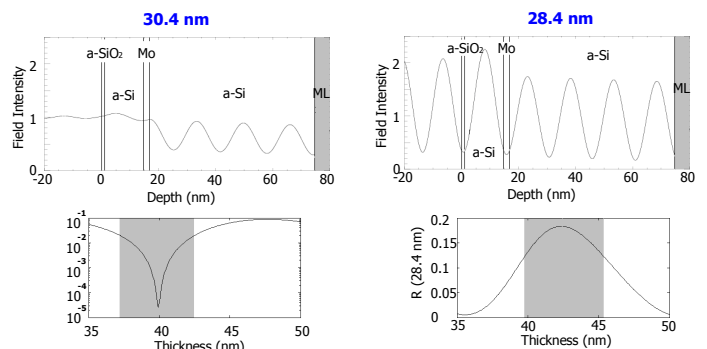
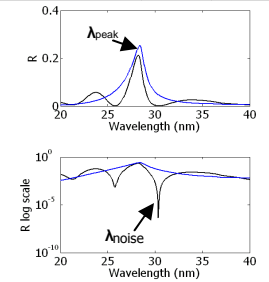
ML	CL	λ_{peak}	λ_{noise}
Mo/Si	Mo/Si	28.4	30.4

Results

	$R_{\lambda_{peak}}$	$R_{\lambda_{noise}}$
Standard periodic	0.25	0.045
Optimized ML + Mo/Si CL	0.196	$2.62 \cdot 10^{-5}$

Multilayer structures

CL Structure	Value
a-Si	14.7 nm
Mo	2.2 nm
a-Si	57.75 nm
Mo	2 nm
ML structure	Value
Period (a-Si/Mo)	151.5 nm
Ratio	0.868
Period number	35



EXPERIMENTAL RESULTS

Multilayer structures

CL Structure	Value
a-Si	15.4 nm
Mo	3.55 nm
a-Si	41.2 nm
Mo	3.55 nm
ML structure	Value
Period (a-Si/Mo)	153 nm
Ratio	0.768
Period number	40

ML+CL structure performance is critically dependent on the optical constants of materials, accordingly an optimized structure design has been derived using the optical constants experimentally measured and reported by Tarrío et al. [*Applied Optics*, Vol. 37, (1998)]. A prototype of this sample has been deposited (RXO) and tested. The reflectivity has been measured with a laser plasma facility D. L. Windt et al. [*Journal of Vacuum Science Technology B* 12, (1994)].

Objectives parameters

ML	CL	λ_{peak}	λ_{noise}
Mo/Si	Mo/Si	28.4	30.4

— Experimental data
 — Theoretical calculation

